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APPLICANTS
 Bin Yu, Sunnyvale, CA; *RP Yes*

** CONTINUING DATA *****
RP None

** FOREIGN APPLICATIONS *****

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
 ** 05/08/2001

Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance met	STATE OR COUNTRY CA	SHEETS DRAWING 1	TOTAL CLAIMS 20	INDEPENDENT CLAIMS 3
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EXAMINER'S SIGNATURE _____ INITIALS _____

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TITLE
 Method of fabricating a semiconductor device having a nitride/high-k/nitride gate dielectric stack by atomic layer deposition (ALD) and a device thereby formed

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